

# **isc Silicon NPN Power Transistor**

#### **DESCRIPTION**

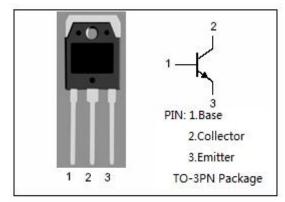
- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= 140V(Min)
- · Good Linearity of hFE
- · High Current Capability
- Wide Area of Safe Operation
- · Complement to Type 2SB817
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

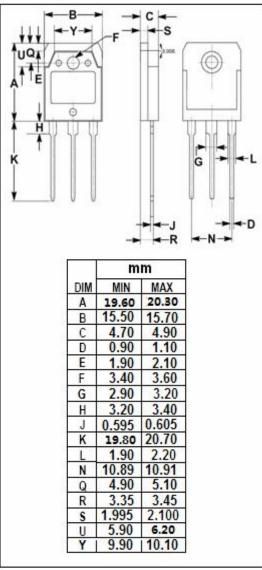
### **APPLICATIONS**

 Recommend for 60W audio frequency amplifier output stage applications

## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	160	V	
Vceo	Collector-Emitter Voltage	140	V	
V <sub>EBO</sub>	Emitter-Base Voltage	tter-Base Voltage 6		
lc	Collector Current-Continuous	12	Α	
Icp	Collector Current-Pulse	15	Α	
Pc	Collector Power Dissipation @ T <sub>C</sub> =25℃	100	W	
Тл	Junction Temperature	150	${\mathbb C}$	
T <sub>stg</sub>	Storage Temperature Range	-40~150	°C	







## **ISC Silicon NPN Power Transistor**

2SD1047

#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 30mA ; R <sub>BE</sub> = ∞	140			V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =1mA; I <sub>E</sub> = 0	160			V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 5mA; I <sub>C</sub> = 0	6			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 5.0A; I <sub>B</sub> = 0.5A		0.6	2.5	V
V <sub>BE(on)</sub>	Base -Emitter On Voltage	I <sub>C</sub> = 1A; V <sub>CE</sub> = 5V			1.5	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 80V ; I <sub>E</sub> = 0			100	μА
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 4V; I <sub>C</sub> = 0			100	μА
h <sub>FE-1</sub>	DC Current Gain	Ic= 1A; VcE= 5V	60		200	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 6A; V <sub>CE</sub> = 5V	20			

## ♦ h<sub>FE-1</sub> Classifications

D	E
60-120	100-200

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